

Title (en)
METHOD AND MEANS OF FABRICATING A SEMICONDUCTOR DEVICE PACKAGE

Publication
EP 0344259 A4 19910424 (EN)

Application
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Priority
US 11522887 A 19871030

Abstract (en)
[origin: WO8904552A1] A semiconductor device assembly is made without a molded package by using a tape having a patterned insulating layer (12) and a conductive layer (14) joined thereto. A semiconductor die (24) is seated on the conductive layer (14) and electrically connected to leads of the patterned conductive layer (14). A body frame (40) is positioned around the die (24) and electrical leads and connections, and an encapsulant material (28) is distributed over the frame (40) and within the frame (40) over the die (24) and electrical leads and connections.

IPC 1-7
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IPC 8 full level
H01L 21/50 (2006.01); **H01L 23/02** (2006.01); **H01L 23/04** (2006.01); **H01L 23/24** (2006.01); **H01L 23/31** (2006.01); **H01L 23/48** (2006.01); **H01L 23/498** (2006.01); **H01L 25/04** (2006.01); **H01L 25/18** (2006.01)

CPC (source: EP KR)
H01L 21/50 (2013.01 - EP); **H01L 23/3121** (2013.01 - EP); **H01L 23/3135** (2013.01 - EP); **H01L 23/48** (2013.01 - KR); **H01L 23/4985** (2013.01 - EP); **H01L 24/45** (2013.01 - EP); **H01L 24/48** (2013.01 - EP); **H01L 2224/16** (2013.01 - EP); **H01L 2224/16225** (2013.01 - EP); **H01L 2224/32145** (2013.01 - EP); **H01L 2224/45144** (2013.01 - EP); **H01L 2224/48091** (2013.01 - EP); **H01L 2224/73265** (2013.01 - EP); **H01L 2224/92247** (2013.01 - EP); **H01L 2924/00014** (2013.01 - EP); **H01L 2924/01014** (2013.01 - EP); **H01L 2924/01079** (2013.01 - EP); **H01L 2924/14** (2013.01 - EP); **H01L 2924/181** (2013.01 - EP)

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